



UD info Corp.

Industrial SD Card SDC-09UG Series Product DataSheet

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Revision History

Revision	Draft Date	History	Author
1.0	2021/9/9	New release	Golden Lee
1.1	2021/10/5	Update performance	Golden Lee
1.2	2022/9/20	Added BiCS5 wide temperature support	Golden Lee





Product Overview

- Capacity
 - TLC: 64GB up to 256GB
 - pSLC: 16GB up to 128GB
- Flash Type
 - Kioxia BiCS5
- Bus Speed Mode
 - Up to UHS-104
- Performance
 - Read up to 95MB/s
 - Write up to 85MB/s
- Power Consumption^{Note1}
 - Power Up Current < 250uA
 - Standby Current < 1mA
 - Read Current < 400mA</p>
 - Write Current < 400mA
 - CPRM Optional (Content Protection for Recordable Media)

- MTBF
 - More than 3,000,000 hours
- Advanced Flash Management
 - Static and Dynamic Wear Leveling
 - Bad Block Management
 - SMART
 - Auto-Read Refresh
 - Embedded Mode
- Supply Voltage 2.7V ~ 3.6V
- Temperature Range
 - Operation Temperature:
 - Standard/Gold: -25°C ~ 85°C
 - ➢ Wide: -40°C ~ 85°C
 - Storage: -40°C ~ 85°C
- RoHS Compliant
- EMI Compliant

Notes:

1. Please see "Power Consumption" for details.



Performance

		Specif	ication			Test Metrix Performance		
Capacity				APP	Flash Configuration	Read	Write	
	Class	UHS-I	vsc	Class		(MB/s)	(MB/s)	
64GB	CL10	U3	V30	A2	512Gb x1, BiCS5, TLC	95	50	
128GB	CL10	U3	V30	A2	512Gb x2, BiCS5, TLC	95	85	
256GB	CL10	U3	V30	A2	512Gb x4, BiCS5, TLC	95	85	
16GB	CL10	U3	V30	A2	512Gb x1, BiCS5, pSLC	95	85	
32GB	CL10	U3	V30	A2	512Gb x2, BiCS5, pSLC	95	85	
64GB	CL10	U3	V30	A2	512Gb x3, BiCS5, pSLC	95	85	
128GB	CL10	U3	V30	A2	512Gb x6, BiCS5, pSLC	95	85	



1.1. General Description

The Secure Digital (SD) card is fully compliant with the standards released by the SD Card Association. The Command List supports [Part 1 Physical Layer Specification Ver6.10 Final] definitions. Card capacities of the nonsecure area and secure area (if needed) support [Part 3 Security Specification Ver4.00 Final] Specifications.

The SD card comes with an 9-pin interface, designed to operate at a maximum frequency of 208MHz. It can alternate communication protocol between the SD mode and SPI mode. It performs data error detection and correction with very low power consumption. SD card are one of the most popular removable storage cards today due to its high performance, good reliability and wide compatibility.



2. PRODUCT SPECIFICATIONS

- Capacity
 - TLC: 64GB up to 256GB
 - pSLC: 16GB up to 128GB
- Compliant Specifications SD Memory Card Specifications:
 - Compliant with Part 1 Physical Layer Specification Ver. 6.10
 - Compliant with Part 2 File System Specification Ver. 3.00
 - Compliant with Part 3 Security Specification Ver. 7.00
- Standard Size SD Card Mechanical Addendum Ver. 7.0
- Card capacity of non-secure area and secure area support [Part 3 Security Specification Ver4.0 Final] Specifications
- Support SD SPI mode
- Designed for read-only and read/write cards
- Bus Speed Mode (use 4 parallel data lines)
 - Non-UHS mode
 - > Default speed mode: 3.3V signaling, frequency up to 25MHz, up to 12.5 MB/sec
 - High speed mode: 3.3V signaling, frequency up to 50MHz, up to 25 MB/sec
 - UHS-I mode
 - SDR12: SDR up to 25MHz, 1.8V signaling
 - SDR25: SDR up to 50MHz, 1.8V signaling
 - SDR50: 1.8V signaling, frequency up to 100MHz, up to 50 MB/sec
 - SDR104: 1.8V signaling, frequency up to 208MHz, up to 104 MB/sec
 - DDR50: 1.8V signaling, frequency up to 50MHz, sampled on both clock edges, up to 50 MB/sec

Note:

- 1. Timing in 1.8V signaling is different from that of 3.3V signaling.
- 2. To properly run the UHS mode, please ensure the device supports UHS-I mode.
- The command list supports [Part 1 Physical Layer Specification Ver6.10] definitions
 - Command list are described in "Table 3-2 SD mode Command Set" and "Table 3-3 SPI mode Command Set" in this document
- Copyrights Protection Mechanism





- Compliant with the highest security of SDMI standard
- Support CPRM (Content Protection for Recordable Media) of SD Card
 - Compliant with [Physical Layer Specification Ver6.10 Final] CPRM optional definition.
 Note: CPRM card is compliant with [Physical Layer Specification Ver5.10 Final]
- Support Hot Plug
 - Card removal during read operation will never harm the content
- Password Protection of cards (optional)
- Designed for read intensive and write intensive cards
- Built-in write protection features (permanent and temporary)
- Write Protect feature using mechanical switch (Full SD Card only)
- ESD protection in contact pads
- ESD protection in pads (contact discharge).
- ESD protection in non-contact pad area (air discharge).
- Operation voltage range: 2.7 ~ 3.6V
- Temperature Range
 - Operation Temp. (Standard/Gold): -25°C ~ 85°C
- Operation Temp. (Wide): -40°C ~ 85°C
- Storage Temp. Range: -40°C ~ 85°C



3. ELECTRICAL INTERFACE OUTLINE

3.1. Pins Assignment and Descriptions



Figure 3-1 SD Card Pin assignment

Table 3-1 SD Memory Card Pad Assignment

nin		SD N	lode		SF	ข Mode
ріп	Name	Type ¹	Description	Name	Туре	Description
1	CD/DAT3 ²	I/O/PP ³	Card Detect/ Data Line[bit3]	CS	l ³	Chip Select (neg. true)
2	CMD	РР	Command/Response	DI	_	Data In
3	VSS1	S	Supply voltage ground	VSS	S	Supply voltage ground
4	VDD	S	Supply voltage	VDD	S	Supply voltage
5	CLK	Ι	Clock	SCLK		Clock
6	VSS2	S	Supply voltage ground	VSS2	s 🧹	Supply voltage ground
7	DAT0	I/O/PP	Data Line[bit0]	DO	O/PP	Data Out
8	DAT1	I/O/PP	Data Line[bit1]	RSV		
9	DAT2	I/O/PP	Data Line[bit2]	RSV		- 459

(1) S: power supply, I: input; O: output using push-pull drivers; PP: I/O using push-pull drivers

(2) The extended DAT lines (DAT1-DAT3) are input on power up. They start to operate as DAT lines after SET_BUS_WIDTH command. The Host shall keep its own DAT1-DAT3 lines in input mode, as well, while they are not used. It is defined so, in order to keep compatibility to MultiMedia Cards.

(3) At power up this line has a 50KOhm pull up enabled in the card. This resistor serves two functions Card detection and Mode Selection. For Mode Selection, the host can drive the line high or let it be pulled high to select SD mode. If the host wants to select SPI mode it should drive the line low. For Card detection, the host detects that the line is pulled high. This pull-up should be disconnected by the user during regular data transfer period, with SET_CLR_CARD_DETECT (ACMD42) command.



3.2. SD Bus Topology

The microSD card supports 2 alternative communication protocols, SD and SPI BUS mode. Host can choose either one of both bus mode, same data can be read or written by both modes. SD mode allows 4-bits data transfer way, it provides high performance. SPI mode supports 1-bit data transfer and of course the performance is lower compared to SD mode.

3.3.SD Bus Mode Protocol

In default speed, the SD Memory Card bus has a single master (application); multiple slaves (Cards), synchronous star topology (refer to Figure 3-2). In high speed and UHS-I, the SD Memory Card bus has a single master (application) and single slave (card), synchronous point to point topology. Clock, power and ground signals are common to all cards. Command (CMD) and data (DAT0-DAT3) signals are dedicated to each card providing continues point to point connection to all the cards.

During initialization process commands are sent to each card individually, allowing the application to detect the cards and assign logical addresses to the physical slots. Data is always sent (received) to (from) each card individually. However, in order to simply the handling of the card stack, after the initialization process, all commands may be sent concurrently to all cards. Addressing information is provided in the command packet. SD bus allows dynamic configuration of the number of data lines. After power up, by default, the SD Memory Card will use only DATO for data transfer. After initialization the host can change the bus width (number of data active lines). This feature allows easy tradeoff between HW cost and system performance. Note that while DAT1 to DAT3 are not in use, the related Host's DAT lines should be in tri-state (input mode). For SDIO cards DAT1 and DAT2 are used for signaling.



Figure 3-2 SD Memory Card System Bus Topology



The SD bus includes the following signals:

CLK: Host to card clock signal

CMD: Bidirectional Command/Response signal

DATO-DAT3: 4 Bidirectional data signals

VDD, Vss1, Vss2: Power and ground signals

Card	0	1	2	3	4	5	6	7	8	9	10	11
Command Class (CCC)	Basic	Comm and Queue	Block read	Reserv ed	Block Write	Erase	Write Protect -ion	Lock Card	Applica tion Specifi c	I/O mode	Switch	Extensi on
CMD0	+	×										
CMD2	+											
CMD3	+											
CMD4	+		, j	1								
CMD5		fil.			1					+		
CMD6			A. S. S.								+	
CMD7	+	and the second s	-			1						
CMD8	+			L.			<	9/				
CMD9	+	and the second			J. S.							
CMD10	+		- Aller					100				
CMD11	+											
CMD12	+				-	~/			1			
CMD13	+				All and a				\sim		2	
CMD15	+				4	2						
CMD16			+		+		-	+			0.	
CMD17			+						720		1	
CMD18			+					1	10,000			Sec.
CMD19			+							<u>~ 6</u>	50	
CMD20			+		+						- 6	
CMD21												+
CMD23			+		+							
CMD24					+							
CMD25					+							
CMD27					+							
CMD28							+					
CMD29							+					
CMD30							+					
CMD32						+						
CMD33						+						

Table 3-2 SD Mode Command Set



Card	0	1	2	3	4	5	6	7	8	9	10	11
Command Class (CCC)	Basic	Comm and Queue	Block read	Reserv ed	Block Write	Erase	Write Protect -ion	Lock Card	Applica tion Specifi c	I/O mode	Switch	Extensi on
CMD34											+	
CMD35											+	
CMD36											+	
CMD37											+	
CMD38						+						
CMD40								+				
CMD42	Aller							+				
CMD43		> +										
CMD44		+	_									
CMD45	1	+										
CMD46		+										
CMD47		+	1	and the second s								
CMD48		l l	and a start of the									+
CMD49			9		A	3						+
CMD50	-	and the second sec									+	
CMD52										+		
CMD53			-		1					+		
CMD55									+			
CMD56					4				+		~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	
CMD57					117						+	
CMD58												+
CMD59						in an					1	+
ACMD6							-		Ŧ			
ACMD13								1	+			
ACMD14									+			
ACMD15									+		2-1	
ACMD16									+			
ACMD22									+			
ACMD23									+			
ACMD28									+			
ACMD41									+			
ACMD42									+			
ACMD51									+			



Commands	Support Requirements
CMD0	Mandatory
CMD2	Mandatory
CMD3	Mandatory
CMD4	Mandatory
CMD5	Optional
CMD6	Mandatory for cards version 1.10 and after
CMD7	Mandatory
CMD8	Mandatory for cards version 2.00 and after
CMD9	Mandatory
CMD10	Mandatory
CMD11	Mandatory for cards supporting UHS-I.
CMDII	Optional for cards that do not support UHS-I.
CMD12	Mandatory
CMD13	Mandatory
CMD15	Mandatory
CMD16	Mandatory
CMD17	Mandatory
CMD18	Mandatory
	Mandatory for cards supporting UHS-1.
CINID19	Optional for cards that do not support UHS-I.
	Not supported for SDSC cards.
	Mandatory for SDHC and SDXC cards that support Video Speed Class.
	Optional for SDHC cards that support:
CMD20	a.) Speed Class; or
	b.) UHS Speed Grade,
	and do not support Video Speed Class
	Mandatory for SDXC cards that support Speed Class or UHS Speed Grade.
CMD21	Optional
	Not supported for SDSC cards.
CMD23	Mandatory for SDHC and SDXC cards that support UHS104.
	Optional for SDHC and SDXC cards that do not support UHS104.
CMD24	Mandatory for writable types of cards
CMD25	Mandatory for writable types of cards
CMD27	Mandatory for writable types of cards
CMD28	Optional
CMD29	Optional

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Commands	Support Requirements
CMD30	Optional
CMD32	Mandatory for writable types of cards
CMD33	Mandatory for writable types of cards
CMD34 - 37	Optional for cards version 1.10 and after
CMD28	Mandatory for writable types of cards
CIVID38	Discard and FULE supports optional
CMD40	Optional
	Optional for cards version 1.01 and 1.10
CMD42	Mandatory for cards version 2.00 and after
	COP support is optional for CMD42
CMD43 - 47	Mandatory for cards supporting Command Queue
CMD48	Optional
CIVID48	Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2)
CMD49	Optional
CIVID45	Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2)
CMD50	Optional for cards version 1.10 and after
CMD52	Optional
CMD53	Optional
CMD55	Mandatory
CMD56	Mandatory
CMD57	Optional for cards version 1.10 and after
CMD58	Optional
CMD59	Optional
ACMD6	Mandatory
ACMD13	Mandatory
ACMD14	Optional
ACMD15	Optional
ACMD16	Optional
ACMD22	Mandatory for writable types of cards
ACMD23	Mandatory for writable types of cards
ACMD28	Optional
ACMD41	Mandatory
ACMD42	Mandatory
ACMD51	Mandatory



3.4. SPI Bus Mode Protocol

While the SD Memory Card channel is based on command and data bit streams that are initiated by a start bit and terminated by a stop bit, the SPI channel by byte oriented. Every command or data block is built for 8-bit bytes and is byte aligned with the CS signal (i.e. the length is a multiple of 8 clock cycles). The card starts to count SPI bus clock cycle at the assertion of the CS signal. Every command or data token shall be aligned with 8-clock cycle boundary.

Similar to the SD Memory Card Protocol, the SPI messages consist of command, response and data-block tokens.

The advantage of SPI mode is reducing the host design effort, especially for MMC host side, it just be modified by little change. Note: please use SD card specification to implement SPI mode function, not use MMC specification. For example, SPI mode is initialized by ACMD41, and the registers are different from MMC card, especially CSD register.



Figure 3-3 SD Memory Card State Diagram (SPI mode)



Table 3-3 SPI Mode Command Set

Card Com	nmand Class CCC)	0	1	2	3	4	5	6	7	8	9	10	11
Supported commands	Class Description	Basic	Reser ved	Block read	Reser ved	Block Write	Erase	Write Protec tion	Lock Card	Applic ation Specifi c	I/O mode	Switch	Reser ved
CMD0	Mandatory	+											
CMD1	Mandatory	+											
CMD5	Optional										+		
CMD6 ²	Mandatory											+	
CMD8 ³	Mandatory	+											
CMD9	Mandatory	+											
CMD10	Mandatory	+											
CMD12	Mandatory	+											
CMD13	Mandatory	+		-									
CMD16	Mandatory	6		+		+			+				
CMD17	Mandatory	1	and the second se	+)								
CMD18	Mandatory		_	+		2							
CMD24	Mandatory ¹				1	+	4						
CMD25	Mandatory ¹	4			and the second s	+		2					
CMD27	Mandatory ¹			100		+							
CMD28	Optional							+	000			250	
CMD29	Optional							+	2	p-1			
CMD30	Optional				10			+		7			
CMD32	Mandatory ¹				4	5	+	\leq				Con-	
CMD33	Mandatory ¹						+				p."	18-	
CMD34	Optional						7		1		CZ	+	and the second s
CMD35	Optional										And and a second	+	
CMD36	Optional										30	+	
CMD37 ²	Optional											+	
CMD38	Mandatory ¹						+						
CMD42 ⁴	(Note 4)								+				
CMD50 ²	Optional											+	
CMD52	Optional										+		
CMD53	Optional										+		
CMD55	Mandatory									+			
CMD56	Mandatory									+			
CMD57 ²	Optional											+	
CMD58	Mandatory	+											
CMD59	Mandatory	+											



Card Command Class (CCC)		0	1	2	3	4	5	6	7	8	9	10	11
Supported commands	Class Description	Basic	Reser ved	Block read	Reser ved	Block Write	Erase	Write Protec tion	Lock Card	Applic ation Specifi c	I/O mode	Switch	Extens ion
ACMD13	Mandatory									+			
ACMD22	Mandatory ¹									+			
ACMD23	Mandatory ¹									+			
ACMD41	Mandatory									+			
ACMD42	Mandatory									+			
ACMD51	Mandatory									+			

Note:

(1) The commands related write and erase are mandatory only for the Writable types of Cards.

(2) This command was defined in spec version 1.10.

- (3) This command is newly defined in version 2.00.
- (4) This command is optional in version 1.01 and 1.10 and mandatory from version 2.00.

COP support is optional for CMD42.



3.5.SD/microSD card initialization

Figure 3-4 presents the initialization flow chart for UHS-I hosts and Figure 3-5 shows sequence of commands to perform voltage switch.



Figure 3-5 ACMD41 Timing Followed by Voltage Switch Sequence

When signaling level is 3.3V, host repeats to issue ACMD41 with HCS=1 and S18R=1 until the response indicates ready. The argument (HCS and S18R) of the first ACMD41 is effective but the all following ACMD41 should be issued with the same argument.



If Bit31 indicates ready, host needs to check CCS and S18A.

The card indicates S18A=0, which means that voltage switch is not allowed and the host needs to use current signaling level.

Current Signaling Level	S18R	S18A	Comment
	0	0	1.8V signaling is not requested
3.3V	1	The card does not support 18 signaling	
	1	1	Start signal voltage switch sequence
1.8V	Х	0	Already switched to 1.8V

Table 3-4 S18R and S18A Combinations

To change signaling level at the same time between host and card, signal voltage switch sequence is invoked by CMD11 as shown in Figure 3-6. CMD11 is issued only when S18A=1 in the response of ACMD41.



Figure 3-6 Signal Voltage Switch Sequence



4. ENVIRONMENTAL SPECIFICATIONS

4.1. Environmental Conditions

Temperature and Humidity

- Storage Temperature Range
 - -40°C ~ 85°C
- Operation Temperature Range
 - Standard/Gold Temperature: -25°C ~ 85°C
 - Wide Temperature: -40°C ~ 85°C

Table 4-1 High Temperature Test Condition (Standard/Gold)

	Temperature	Humidity	Test Time
Operation	85°C	0% RH	168 hours
Storage	85°C	0% RH	500 hours

Result: No any abnormality is detected.

Table 4-2 High Temperature Test Condition (Wide)

	Temperature	Humidity	Test Time
Operation	85°C	0% RH	300 hours
Storage	85°C	0% RH	500 hours

Result: No any abnormality is detected.

Table 4-3 Low Temperature Test Condition (Standard/Gold)

	Temperature	Humidity	Test Time
Operation	-25°C	0% RH	168 hours
Storage	-40°C	0% RH	300 hours 🤍

Result: No any abnormality is detected.

Table 4-4 Low Temperature Test Condition (Wide)

	Temperature	Humidity	Test Time
Operation	-40°C	0% RH	168 hours
Storage	-40°C	0% RH	500 hours

Result: No any abnormality is detected.





	• •		•
	Temperature	Humidity	Test Time
Operation	40°C	95% RH	4 hours
Storage	40°C	95% RH	500 hours

Table 4-5 High Humidity Test Condition (Standard/Gold)

Result: No any abnormality is detected.

Table 4-6 High Humidity Test Condition (Wide)

	Temperature	Humidity	Test Time
Operation	55°C	95% RH	4 hours
Storage	55°C	95% RH	500 hours

Result: No any abnormality is detected.

Table 4-7 Temperature Cycle Test (Standard/Gold)

	Temperature	Test Time	Cycle	
Operation	-25°C	30 min	20 Cycles	
Operation	85°C	30 min		
Storage	-40°C	30 min	20 Cuelos	
	85°C	30 min	20 Cycles	

Result: No any abnormality is detected.

Table 4-8 Temperature Cycle Test (Wide)

	- Nightan - William			
	Temperature	Test Time	Cycle	
Operation	-40°C	30 min	20 Cycles	
	85°C	30 min		
Storage	-40°C	30 min	EQ Cucles	
	85°C	30 min	SUCYCles	

Result: No any abnormality is detected



Shock

Table 4-9 Shock Specification

	Acceleration Force	Half Sin Pulse Duration
Industrial SD/microSD	1500G	0.5ms

Result: No any abnormality is detected when power on.

Vibration

Table 4-10 Vibration Specification

	Condition		Vibration
Frequency/Displacement Frequency/Acceleration		Orientation	
Industrial	20Hz~80Hz/1 52mm	80Hz~2000Hz/20G	X, Y, Z axis/30 min
SD/microSD	20112 80112/1.3211111	52mm 80Hz*2000Hz/20G	for each

Result: No any abnormality is detected when power on.

Drop

Table 4-11 Drop Specification

	Height of Drop	Number of Drop
Industrial SD/microSD	150cm free fall	6 face of each unit

Result: No any abnormality is detected when power on.

Bending

Table 4-12 Bending Specification

			Sec. 1
	Force	Action	
Industrial SD/microSD	≥ 10N	Hold 1min/5times	1

Result: No any abnormality is detected when power on."

Torque

Table 4-13 Torque Specification

	Force	Action
Industrial SD/microSD	0.1N-m or +/-2.5 deg	Hold 30 seconds/5times

Result: No any abnormality is detected when power on.



Salt Spray Test

Table 4-14 Salt Spray Specification

	Condition	Action	
Industrial SD/microSD	Concentration: 3% NaCl	Storage for 24 brs	
	Temperature: 35°C	Storage for 24 firs	

Result: No any abnormality is detected when power on.

Waterproof Test

Table 4-15 Waterproof Specification

	Condition	Action
	Water temperature: 25°C	
Industrial SD/microSD	Water depth: The lowest point of unit is	Storage for 30 mins
	locating 1000mm below surface.	

Result: JIS IPX7 compliance. No any abnormality is detected when power on.

Test X-Ray Exposure Test

Table 4-16 X-Ray Exposure Specification

	Condition	Action
	0.1 Gy of medium-energy radiation (70	
Industrial SD/microSD	keV to 140 keV, cumulative dose per	Storage for 30 mins
	year) to both sides of the card.	

Result: ISO 7816-1 compliance. No any abnormality is detected when power on.

Switch Cycle Test

Table 4-17 Switch Cycle Test

	Applied Force	Result
Industrial SD/microSD	0.4 ~ 0.5N	
	1000 times	PA33

Result: No any abnormality is detected when power on.

Durability Test

Table 4-18 Durability Test

	Mating cycle	Result	
Industrial SD/microSD	10000 times	PASS	

Result: No any abnormality is detected when power on.



Electrostatic Discharge (ESD)

Table 4-19 Contact ESD Specification

	Condition	Result
Industrial SD/microSD	Contact: ± 4KV each item 25 times	
	Air: ± 8KV 10 times	PASS

EMI Compliance

- FCC: CISPR22
- CE: EN55032
- BSMI 13438

4.2. MTBF

MTBF, an acronym for Mean Time between Failures, is a measure of a device's reliability. Its value represents the average time between a repair and the next failure. The measure is typically in units of hours. The higher the MTBF value, the higher the reliability of the device. The predicted result of UDinfo's SD/microSD is more than 3,000,000 hours.

Analysis software: Relex7.3

Analysis Method: Telcordia SR-332, Reliability Prediction of Electronic Equipment.

Operational Temperature(Ta) of test environment: 30°C

Temperature(Tc) of Device when evaluation: 45° C



	SD6.10 SDSC	SD6.10 SDHC	SD6.10 SDXC
File System	FAT 12/16	FAT32	exFAT
Addressing Mede	Byte	Block	Block
	(1 byte unit)	(512 byte unit)	(512 byte unit)
HCS/CCS bits of ACMD41	Support	Support	Support
CMD8 (SEND_IF_COND)	Support	Support	Support
CMD16 (SET DIOCVIENI)	Support	Support	Support
CMD18 (SET_BLOCKLEN)	Support	(Only CMD42)	(Only CMD42)
Partial Read	Support	Not Support	Not Support
Lock/Unlock Function	Mandatory	Mandatory	Mandatory
Write Protect Groups	Optional	Not Support	Not Support
Supply Voltage 2.0v – 2.7v (for initialization)	Not Support	Not Support	Not Support
Total Bus Capacitance for each signal line	40pF	40pF	40pF
CSD Version (CSD_STRUCTURE Value)	1.0 (0x0)	2.0 (0x1)	2.0 (0x1)
Speed Class	Ontional	Mandatory	Mandatory
	Optional	(Class 2 / 4 / 6 / 10)	(Class 2 / 4 / 6 / 10)

Table 5-1 Comparing SDSC, SDHC, and SDXC

Table 5-2 Comparing UHS Speed Grade Symbols

	WORK WAS AND		
	U1 (UHS Speed Grade 1)	U3 (UHS Speed Grade 3)	
Operable Under	*UHS-I Bus I/F, UHS-II Bus I/F		
SD Memory Card	SDHC UHS-I and UHS-II, SDXC UHS-I and UHS-II		
Mark	1	3	
Performance	10 MB/s minimum write speed	30 MB/s minimum write speed	
Applications	Full higher potential of recording real-time broadcasts and capturing large- size HD videos.	Capable of recording 4K2K video.	

*UHS (Ultra High Speed), the fastest performance category available today, defines bus-interface speeds up to 312 Megabytes per second for greater device performance. It is available on SDXC and SDHC memory cards and devices.



Ø.,

6.1. Power Consumption

The table below is the power consumption of microSD card with different flash memory types.

Flash Mode		Max. Power Up	Max. Standby	Max. Read	Max. Write
		Current (uA)	Current (uA)	Current (mA)	Current (mA)
Default Speed Mode		250	1000	150 @3.6V	150 ³ @3.6V
High Speed Mode		250	1000	200 @3.6V	200 @3.6V
UHS50/DDR50		250	1000	400 @3.6V	400 @3.6V
UHS-I Mode	UHS104/DDR50	250	1000	400 @3.6V	400 @3.6V

Note:

- 1. Power consumptions are measured at room temperature.
- 2. Power consumption of Max. Standby Current is for SD cards under and including 64GB only. For 128GB and 256GB, the power consumption is to be determined.
- 3. For SDXC, up to 100mA from VDD1 when XPC=0; up to 150mA from VDD1 when XPC=1.

6.2. Electrical Specifications

6.2.1. Absolute Maximum Rating

						_
Item	Symbol	Parameter	Min.	Max.	Unit	
1	т	Operating Temperature (Standard/Gold)	-25	+85	°C	Sec. St.
T	la	Operating Temperature (Wide)	-40	+85	°C	
2	T _{st}	Storage Temperature	-40	+85	°C	

Parameter	Symbol	Min.	Max.	Unit
Operating Temperature (Standard/Gold)	т	-25	+85	°C
Operating Temperature (Wide)	-40	+85	°C	
V _{DD} Voltage	V _{DD}	2.7	3.6	V



6.3.1. Bus Operation Conditions for 3.3V Signaling

Table 6-1 Threshold Level for High Voltage Range

Parameter	Symbol	Min.	Max	Unit	Condition
Supply Voltage	V _{DD}	2.7	3.6	V	
Output High Voltage	V _{OH}	0.75*V _{DD}		V	I_{OH} =-2mA V_{DD} Min
Output Low Voltage	V _{OL}		0.125*V _{DD}	V	I_{OL} =2mA V_{DD} Min
Input High Voltage	V _{IH}	0.625*V _{DD}	V _{DD} +0.3	V	
Input Low Voltage	VIL	V _{SS} -0.3	0.25*V _{DD}	V	
Power Up Time			250	ms	From 0V to V_{DD} min

Table 6-2 Peak Voltage and Leakage Current

Ta	able 6-2 Pea	ık Voltage a	nd Leakage C	Current					
Parameter	Symbol	Min.	Max	Unit	Remarks				
Peak voltage on all lines		-0.3	V _{DD} +0.3	V					
	All Inputs								
Input Leakage Current	Starte .	-10	10	uA					
		All Outp	uts						
Output Leakage Current		-10	10	uA					

Table 6-3 Threshold Level for 1.8V Signaling

		Party and the second se		2/	
Parameter	Symbol	Min.	Max	Unit	Condition
Supply Voltage	V _{DD}	2.7	3.6	v	
Regulator Voltage	V _{DDIO}	1.7	1.95	>	Generated by V _{DD}
Output High Voltage	V _{OH}	1.4	-	V	I _{он} =-2mA
Output Low Voltage	V _{OL}	-	0.45	V	I _{oL} =2mA
Input High Voltage	V _{IH}	1.27	2.00	V	
Input Low Voltage	V _{IL}	V _{SS} -0.3	0.58	V	

Table 6-4 Input Leakage Current for 1.8V Signaling

Parameter	Symbol	Min.	Max	Unit	Remarks
Input Lookago Current		ſ	n		DAT3 pull-up is
Input Leakage Current		-2	2	uA	disconnected

UD info CORP. TEL: +886-2-7713-6050 FAX: +86-2-8511-3151

3F-4, No.8, Ln. 609, Sec. 5, Chongxin Rd., Sanchong Dist., New Taipei City 241, Taiwan (R.O.C.)



6.3.2. Bus Signal Line Levels

Bus Operation Conditions – Signal Line's Load

Total Bus Capacitance = $C_{HOST} + C_{BUS} + N C_{CARD}$

Parameter	Symbol	Min	Max	Unit	Remark
Pull-up resistance	R _{cmd} R _{dat}	10	100	kΩ	to prevent bus floating
Total bus capacitance for each signal line	CL		40	pF	1 card C _{HOST} + C _{BUS} shall not exceed 30 pF
Card Capacitance for each signal pin	C _{CARD}		10	рF	
Maximum signal line inductance			16	nH	
Pull-up resistance inside card (pin1)	R _{DAT3}	10	90	kΩ	May be used for card detection
Capacity Connected to Power Line	Cc		5	uF	To prevent inrush current

6.3.3. Power Up Time

Host needs to keep power line level less than 0.5V and more than 1ms before power ramp up.



Power On or Power Cycle

Followings are requirements for Power on and Power cycle to assure a reliable SD Card hard reset.

- (1) Voltage level shall be below 0.5V.
- (2) Duration shall be at least 1ms.



Power Supply Ramp Up

The power ramp up time is defined from 0.5V threshold level up to the operating supply voltage which is stable between VDD (min.) and VDD (max.) and host can supply SDCLK.

Followings are recommendation of Power ramp up:

- (1) Voltage of power ramp up should be monotonic as much as possible.
- (2) The minimum ramp up time should be 0.1ms.
- (3) The maximum ramp up time should be 35ms for 2.7-3.6V power supply.
- (4) Host shall wait until VDD is stable.
- (5) After 1ms VDD stable time, host provides at least 74 clocks before issuing the first command.

Power Down and Power Cycle

- When the host shuts down the power, the card VDD shall be lowered to less than 0.5Volt for a minimum period of 1ms. During power down, DAT, CMD, and CLK should be disconnected or driven to logical 0 by the host to avoid a situation that the operating current is drawn through the signal lines.
- If the host needs to change the operating voltage, a power cycle is required. Power cycle means the power is turned off and supplied again. Power cycle is also needed for accessing cards that are already in *Inactive State*. To create a power cycle the host shall follow the power down description before power up the card (i.e. the card VDD shall be once lowered to less than 0.5Volt for a minimum period of 1ms).

6.3.4. Power Up Time of Card

A device shall be ready to accept the first command within 1ms from detecting VDD min. Device may use up

to 74 clocks for preparation before receiving the first command.







Parameter	Symbol	Min	Max	Unit	Remark				
Clock CLK (All values are referred to min(V_{IH}) and max(V_{IL})									
Clock frequency Data Transfer Mode	f _{PP}	0	25	MHz	C _{card} ≤ 10 pF (1 card)				
Clock frequency Identification Mode	f _{OD}	0 ⁽¹⁾ /100	400	KHz	C _{card} ≤ 10 pF (1 card)				
Clock low time	t _{wL}	10		ns	C _{card} ≤ 10 pF (1 card)				
Clock high time	t _{wн}	10		ns	C _{card} ≤ 10 pF (1 card)				
Clock rise time	t_{TLH}		10	ns	C _{card} ≤ 10 pF (1 card)				
Clock fall time	t_{THL}		10	ns	C _{card} ≤ 10 pF (1 card)				
	Inputs CMD,	DAT (referenc	ed to CLK)						
Input set-up time	t _{isu}	5		ns	C _{card} ≤ 10 pF (1 card)				
Input hold time	t _{ін}	5		ns	C _{card} ≤ 10 pF (1 card)				
Outputs CMD, DAT (referenced to CLK)									
Output Delay time during Data Transfer Mode	todly	0	14	ns	C∟ ≤ 40 pF (1 card)				
Output Delay time during Identification Mode	todly	0	50	ns	C∟ ≤ 40 pF (1 card)				

(1) OHz means to stop the clock. The given minimum frequency range is for cases where continuous clock is required.



6.4.2.SD Interface Timing (High-Speed Mode)



Shaded areas are not valid

Parameter	Symbol	Min	Max	Unit	Remark
Clock CL	(All values ar	e referred to n	nin(V⊮) and m	ax(V⊫)	
Clock frequency Data Transfer	f	0	50		$C_{card} \le 10 \text{ pF}$
Mode	Трр	0	50	IVITIZ	(1 card)
Clock low time	t	7		nc	$C_{card} \le 10 \text{ pF}$
	τwL			113	(1 card)
Clock high time	t		1 / 1	nc	C _{card} ≤ 10 pF
	CWH			113	(1 card)
Clock rise time	t	And	2	ns	$C_{card} \le 10 \text{ pF}$
	CILH	10		113	(1 card)
Clock fall time	t		3	nc	$C_{card} \le 10 \text{ pF}$
	CIAL		5		(1 card)
	Inputs CMD,	DAT (referenc	ed to CLK)		
Innut set-un time	+	6		ns	$C_{card} \le 10 \text{ pF}$
	C ISU	0		115	(1 card)
Input hold time	t	2		nc	$C_{card} \le 10 \text{ pF}$
	ЧН	2		115	(1 card)
	Outputs CMD	, DAT (referen	ced to CLK)	-	
Output Delay time during Data	+		14	nc	C _L ≤ 40 pF
Transfer Mode	CODLY		14	115	(1 card)
Output Hold time	Тан	25		nc	C∟≤ 15 pF
	ОН	2.5		115	(1 card)
Total System capacitance of	C		40	nE	CL ≤ 15 pF
each line ¹			40	Ч	(1 card)

(1) In order to satisfy severe timing, the host shall drive only one card.



6.4.3.SD Interface Timing (SDR12, SDR25, SDR50 and SDR104 Modes) Input



Symbol	Min	Max	Unit	Remark
t _{CLK}	4.80	-	ns	208MHz (Max.), Between rising edge, V _{CT} = 0.975V
t _{CR} , t _{CF}		0.2* t _{ськ}	ns	t_{CR} , $t_{CF} < 0.96$ ns (max.) at 208MHz, CCARD=10pF t_{CR} , $t_{CF} < 2.00$ ns (max.) at 100MHz, CCARD=10pF The absolute maximum value of t_{CR} , t_{CF} is 10ns regardless of clock frequency
Clock Duty	30	70	%	

Clock Signal Timing

SDR50 and SDR104 Input Timing:



Symbol	Min	Max	Unit	SDR104 Mode
t _{is}	1.40	-	ns	C _{CARD} =10pF, V _{CT} = 0.975V
t _{IH}	0.8	-	ns	C _{CARD} =5pF, V _{CT} = 0.975V
Symbol	Min	Max	Unit	SDR50 Mode
tıs	3.00	-	ns	C _{CARD} =10pF, V _{CT} = 0.975V
t _{IH}	0.8	-	ns	C _{CARD} =5pF, V _{CT} = 0.975V

Card Input Timing



<u>Output</u>

Output (SDR12, SDR25, SDR50 mode):



	Symbol	Min	Max	Unit	Remark
6	todly	-	7.5	ns	t_{CLK} >=10.0ns, CL=30pF, using driver Type B, for SDR50
	todly	-	14	ns	t _{CLK} >=20.0ns, C _L =40pF, using driver Type B, for SDR25 and SDR12,
	Тон	1.5	-	ns	Hold time at the t_{ODLY} (min.), $C_L=15pF$

Output Timing of Fixed Data Window (SDR12, SDR25, SDR50 modes)

Output (SDR104 mode):



Symbol	Min	Max	Unit	Remark
t _{OP}	-	2	UI	Card Output Phase
∆t _{op}	-350	+1550	ps	Delay variable due to temperature change after tuning
t _{odw}	0.60	-	UI	t _{oDW} = 2.88ns at 208MHz



6.4.4.SD Interface Timing (DDR50 Modes)



Symbol	Min	Max	Unit	Remark
t _{clk}	20	-	ns	50MHz (Max.), Between rising edge
t _{CR} , t _{CF}	- 4	0.2 * t _{CLK}	ns	$t_{\text{CR}}, t_{\text{CF}}$ < 4.00ns (max.) at 50MHz, C_{CARD}=10pF
Clock Duty	45	55	%	



Timing Diagram DAT Inputs/Outputs Reference to CLK in DDR50 mode



Parameter	Symbol	Min	Max	Unit	Remark			
Input CMD (referenced to CLK rising edge)								
Input set-up time	t _{isu}	3	-	ns	C _{card} ≤ 10 pF (1 card)			
Input hold time	t _{ін}	0.8	-	ns	C _{card} ≤ 10 pF (1 card)			
Output CMD (referenced to CLK rising edge)								
Output Delay time during Data Transfer Mode	ime during Data t _{ODLY} 13.7		ns	C _L ≤ 30 pF (1 card)				
Output Hold time	Т _{он}	1.5	-	ns	C _L ≥ 15 pF (1 card)			
Inputs DAT (referenced to CLK rising and falling edges)								
Input set-up time	t _{ISU2x}	3	-	ns	C _{card} ≤10 pF (1 card)			
Input hold time	t _{iH2x}	0.8	-	ns	C _{card} ≤10 pF (1 card)			
Outputs DAT (referenced to CLK rising and falling edges)								
Output Delay time during Data Transfer Mode	t _{odly2x}	-	7.0	ns	C∟≤ 25 pF (1 card)			
Output Hold time	T _{OH2x}	1.5		ns	C _L ≥ 15 pF (1 card)			

Bus Timing – Parameter Values (DDR50 mode)



7. HOST SYSTEM DESIGN GUIDELINES



7.1. Efficient Data Writing to SD Memory Card

In order to optimize sequential writing performance and WAF (Write Amplification Factor), it is recommended to use allocation unit (AU) writing.

It is recommended that Multiple_Block_Write shall be used as a command for writing data, and the size of data written by each command should be the FAT cluster x n (n: integer)

7.1.1.Write_Single_Block and Write_Multiple_Block

Write single block (CMD24) was written by one sector (512Bytes), which is suitable to write small area such like updating file system area (FAT). Besides, Write multiple blocks (CMD25) is a command for writing data to blocks that have sequential address per command, which is suitable to write large area such as user data. Write multiple blocks with a cluster unit (512Byte x 128 Sectors = 64KByte) in the file system is an efficient access to the flash memory, it is obviously to provide higher speed to compared to single write block.

And it could be estimated that SD card internal process would be reduced to save power consumption and flash write amplification factor, that is why the efficient data writing was recommended. To avoid the command issued by 512Bytes with single write block, software processes in the host device become faster. For this operation, check the sectors in the SD card and file system as Figure 7-1



Heading address of user data area shall match with the heading of 64KB boundary of SD logical address.

Figure 7-1 Matching between logical address and file system

Note: Large Cluster unit is better for performance and WAF, for example, 128KB, 256KB or 512KB. Large cluster unit also can save write command numbers and few transfer time.



7.2. Basic Process of Error Handling

7.2.1. Retry Process

Execute the process by sending commands again, especially for signal issue between card and host.

7.2.2. Recovery Process

Confirm card status is in Transfer State, if card status is not in Transfer State, please issue Stop command to recover it and execute or continue flow. If there was UECC during read/write status, we could use recovery process to recover it.

7.2.3. Tuning Write Command Process

In order to adjust Host CMD and CLK timing, the way is issue tuning command to confirm what the device response and data was received by host. Based on the response, host was adjusting the timing step by step and recording the pass range. Through this flow host could adjust the appropriate timing settings to avoid unexpected handshaking issue.

7.2.4. Tuning Read Command Process

In order to adjust Host CLK and DAT timing, the way is issue tuning command to confirm what the device response and data was received by host. Based on the response, host was adjusting the timing step by step and recording the pass range. Through this flow host could adjust the appropriate timing settings to avoid unexpected handshaking issue.

7.2.5. Exception Handling Process

No doubt that sometimes we would face all error handling above could not recover it successfully, and we could react based on the situation.

- If there was error in response, we could re-initialize the card.
- If it was signal issue, we could set up signal status by reading data and tuning command.



7.3. Common Error Handling in SPI and SD mode

7.3.1.Time-out

Run the Retry Process. No response from CMD, it might be signal or status got problem. To avoid the infinite loop, implement a retry counter in the host so that, if the retry counter expires, the exception handling starts in the host.

7.3.2. Error Detect (CMD CRC Error)

Run the Recovery Process. If it got second time failure with CRC, the setting might be too margin to receive response stably. Suggestion is use tuning write command to fix timing and then retry it.

7.3.3. Error Detect (Other Error) in SPI and SD mode

Run the Recovery Process.

7.3.4. Others

Most errors could be recovered by running the Recovery Process, let card come into Transfer State and then executing the flow we planned. If it does not work, please use exception method to come back initial state.

7.4. Data Error Handling in SPI and SD mode

7.4.1.Time-out

Run the Recovery Process. While the state was recovered, run the flow again.

7.4.2. Read CRC16 Error

Run the Recovery Process. If it got second time failure with CRC, the setting might be too margin to receive data stably. Suggestion is use tuning read date to fix timing and then retry it.

7.4.3. Write CRC Status Error

Run the Recovery Process. If it got second time failure with CRC, the setting might be too margin to receive CRC status stably. Suggestion is use tuning read date to fix timing and then retry it.

7.4.4. Others

Most errors could be recovered by running the Recovery Process, let card come into Transfer State and then executing the flow we planned.



7.5. Multiple Block Write (CMD25) Process

- If Response is ADDRESS_OUT_OF_RANGE, please confirm writing address.
- If Response is DEVICE_IS_LOCKED, please stop writing data.
- If Response is COM_CRC_ERROR, run retry or tuning.



Figure 7-2 Multiple Write (CMD25) Error Handling



7.6. Retry Error handling

In order to avoid signal issue caused unexpected response from device, we could use Retry Process to fix it.

- Please make sure card state is in transfer state before issuing following commands.
- To avoid the infinite loop, implement a retry counter in the host.
- If the device could not respond to CMD13 normally, please run exception handling to recover card status.



Figure 7-3 Retry Error Handling Process



7.7. Recovery Error Handling

Sometimes the device failure could not be recovered by Retry Process, it suggests to execute STOP Command

(CMD12) to stop whole commands and response and then run following flow.

- Please confirm card status is in Transfer state.
- In order to avoid infinite loops, host has to set up a retry counter number.





7.8. Tuning Write Command Error Handling

Reconfirm the card's pass range, to make sure card could receive host commands.

- If there was no any pass window, it might be connection issue or signal issue.
- Pass Range depends on frequency level, higher frequency makes fewer pass range.



Figure 7-5 Tuning Write Command Error Handling Process





7.9. Exception Error Handling

- Error in Card's response or data output time-out, it could re-initialize the card.
- If there was CMD CRC7 issue, it could use tuning write command process to find out appropriate timing.
- If there was DAT CRC16 issue, it could use tuning read command process to find out appropriate timing.



Figure 7-6 Exception Error Handling Process



7.10. Multiple Blocks Read (CMD18) Error Handling Process

- If card responded ADDRESS_OUT_OF_Range, please check writing address.
- If card responded DEVICE_IS_LOCKED, please stop writing data.
- If card responded COM_CRC_ERROR, run Retry or Tuning Process.



Figure 7-7 Multiple Blocks Read (CMD18) Error Handling Process



7.11. Tuning Read Data Error Handling

Reconfirm the card's pass range, to make sure host could receive card's Response and Data.

- If there was no any pass window, it might be connection issue or signal issue.
- Pass Range depends on frequency level, higher frequency makes fewer pass range.



Figure 7-8 Tuning Read Data Error Handling Process



8.1. Pad Assignment and Descriptions



Table 8-1 SD Memory Card Pad Assignment

mim		lode	SPI Mode				
ріп	Name	Type ¹	Description	Name	Туре	Description	
1	CD/DAT3 ²	I/O/PP ³	Card Detect/ Data Line[bit3]	CS	l ³	Chip Select (neg. true)	
2	CMD	РР	Command/Response	DI	_	Data In	
3	VSS1	S	Supply voltage ground	VSS	S	Supply voltage ground	
4	VDD	S	Supply voltage	VDD	S	Supply voltage	
5	CLK	I	Clock	SCLK		Clock	
6	VSS2	S	Supply voltage ground	VSS2	s 🤇	Supply voltage ground	
7	DAT0	I/O/PP	Data Line[bit0]	DO	O/PP	Data Out	
8	DAT1	I/O/PP	Data Line[bit1]	RSV			
9	DAT2	I/O/PP	Data Line[bit2]	RSV		- 459	

(1) S: power supply, I: input; O: output using push-pull drivers; PP: I/O using push-pull drivers

(2) The extended DAT lines (DAT1-DAT3) are input on power up. They start to operate as DAT lines after SET_BUS_WIDTH command. The Host shall keep its own DAT1-DAT3 lines in input mode, as well, while they are not used. It is defined so, in order to keep compatibility to MultiMedia Cards.

(3) At power up this line has a 50KOhm pull up enabled in the card. This resistor serves two functions Card detection and Mode Selection. For Mode Selection, the host can drive the line high or let it be pulled high to select SD mode. If the host wants to select SPI mode it should drive the line low. For Card detection, the host detects that the line is pulled high. This pull-up should be disconnected by the user during regular data transfer period, with SET_CLR_CARD_DETECT (ACMD42) command.



Name	Width	Description
CID	128bit	Card identification number; card individual number for identification.
		Mandatory
RCA ¹	16bit	Relative card address; local system address of a card, dynamically suggested
		by the card and approved by the host during initialization. Mandatory
DSR	16bit	Driver Stage Register; to configure the card's output drivers. Optional
CSD	128bit	Card Specific Data; information about the card operation conditions.
		Mandatory
SCR	64bit	SD Configuration Register; information about the SD Memory Card's Special
		Features capabilities. Mandatory
OCR	32bit	Operation conditions register. Mandatory.
SSR	512bit	SD Status; information about the card proprietary features
		Mandatory
OCB	32bit	Card Status; information about the card status
UCK		Mandatory

(1) RCA register is not used (or available) in SPI mode.



9. PHYSICAL DIMENSION

Dimension: 32mm(L) x 24mm(W) x 2.1mm(H)





10. PARTNUMBER DECODER

Product Datasheet

$\mathsf{SDC-09UGX^8X^9X^{10}X^{11}X^{12}X^{13}X^{14}X^{15}}$

$X^1X^2X^3$	X ⁴ X ⁵	X ⁶ X ⁷	X ⁸ X ⁹ X ¹⁰ X ¹¹ X ¹²	X ¹³	X ¹⁴	X ¹⁵
SDC	09	UG	016GB 032GB 064GB 128GB 256GB	 A: 3D TLC Standard (-25°C ~ +85°C) J: 3D TLC Gold (-25°C ~ +85°C) B: 3D TLC Industrial (-40°C ~ +85°C) V: 3D pSLC Standard (-25°C ~ +85°C) G: 3D pSLC Gold (-25°C ~ +85°C) W: 3D pSLC Industrial (-40°C ~ +85°C) 	As bellow	Ρ
X ¹⁴ 2: Spee 4: Spee 6: Spee A: Spee S: UHS T: UHS B: Vide C: Vide C: Vide G: App H: App	ed Class 2 ed Class 4 ed Class 6 ed Class 1 -I Class 1 -I Class 1 eo Speed eo Speed Class 1 (A Class 2 (A	2 (CL2) 4 (CL4) 5 (CL6) 10 (CL10) (UHS-I-U: 6 (V6) 10 (V10) 30 (V30) A1) A2)				